



Standard Recovery Diodes, 250 A to 320 A (MAGN-A-PAK Power Modules)



MAGN-A-PAK

FEATURES

- High voltage
- Electrically isolated base plate
- 3000 V_{RMS} isolating voltage
- Industrial standard package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996 
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

| PRODUCT SUMMARY | |
|--------------------|-------------------------------|
| I _{F(AV)} | 250 A to 320 A |
| Type | Modules - Diode, High Voltage |
| Package | MAGN-A-PAK |
| Circuit | Two SCRs doubler circuit |

DESCRIPTION

This new VS-VSK series of MAGN-A-PAKs uses high voltage power diodes in two basic configurations. The semiconductors are electrically isolated from the metal base, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges and the single diode module can be used in conjunction with the thyristor modules as a freewheel diode. These modules are intended for general purpose applications such as battery chargers, welders and plating equipment and where high voltage and high current are required (motor drives, etc.).

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|-----------------|-------------|-----------|-----------|--------------------|
| SYMBOL | CHARACTERISTICS | VSK.250.. | VSK.270.. | VSK.320.. | UNITS |
| I _{F(AV)} | | 250 | 270 | 320 | A |
| | T _C | 100 | 100 | 100 | °C |
| I _{F(RMS)} | | 393 | 424 | 502 | A |
| I _{FSM} | 50 Hz | 7015 | 8920 | 10 110 | |
| | 60 Hz | 7345 | 9430 | 10 580 | |
| I ² t | 50 Hz | 246 | 398 | 511 | kA ² s |
| | 60 Hz | 225 | 363 | 466 | |
| I ² √t | | 2460 | 3980 | 5110 | kA ² √s |
| V _{RRM} | | 400 to 3000 | | | V |
| T _J | | - 40 to 150 | | | °C |



ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | |
|----------------------------------------|--------------|-----------------------------------------------------------------|---------------------------------------------------------------------|------------------------------------------|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} MAXIMUM AT 150 °C mA |
| VS-VSK.250 VS-VSK.270 VS-VSK.320 | 04 | 400 | 500 | 50 |
| | 08 | 800 | 900 | |
| | 12 | 1200 | 1300 | |
| | 16 | 1600 | 1700 | |
| | 20 | 2000 | 2100 | |
| VS-VSK.270 | 30 | 3000 | 3100 | |

| FORWARD CONDUCTION | | | | | | | | |
|---------------------------------------------------------------|---------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------|-----------------------------------------------------------------------|---------|---------|--------------------|-------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VSK.250 | VSK.270 | VSK.320 | UNITS | |
| Maximum average forward current at case temperature | I _{F(AV)} | 180° conduction, half sine wave | | 250 | 270 | 320 | A | |
| | | | | 100 | 100 | 100 | °C | |
| Maximum RMS forward current | I _{F(RMS)} | As AC switch | | 393 | 424 | 502 | | |
| Maximum peak, one-cycle forward, non-repetitive surge current | I _{FSM} | t = 10 ms | No voltage reappplied | Sinusoidal half wave, initial T _J = T _{J maximum} | 7015 | 8920 | 10 110 | A |
| | | t = 8.3 ms | | | 7345 | 9340 | 10 580 | |
| | | t = 10 ms | 100 % V _{RRM} reappplied | | 5900 | 7500 | 8500 | |
| | | t = 8.3 ms | | | 6180 | 7850 | 8900 | |
| Maximum I ² t for fusing | I ² t | t = 10 ms | No voltage reappplied | | 246 | 398 | 511 | kA ² s |
| | | t = 8.3 ms | | | 225 | 363 | 466 | |
| | | t = 10 ms | 100 % V _{RRM} reappplied | | 174 | 281 | 361 | |
| | | t = 8.3 ms | | | 159 | 257 | 330 | |
| Maximum I ² √t for fusing | I ² √t | t = 0.1 ms to 10 ms, no voltage reappplied | | 2460 | 3980 | 5110 | kA ² /s | |
| Low level value of threshold voltage | V _{F(TO)1} | (16.7 % × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _{J maximum} | | 0.79 | 0.74 | 0.69 | V | |
| High level value of threshold voltage | V _{F(TO)2} | (I > π × I _{F(AV)}), T _J = T _{J maximum} | | 0.92 | 0.87 | 0.86 | | |
| Low level forward slope resistance | r _{f1} | (16.7 % × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _{J maximum} | | 0.63 | 0.94 | 0.59 | mΩ | |
| High level forward slope resistance | r _{f2} | (I > π × I _{F(AV)}), T _J = T _{J maximum} | | 0.49 | 0.81 | 0.44 | | |
| Maximum forward voltage drop | V _{FM} | I _{FM} = π × I _{F(AV)} , T _J = T _{J maximum} , 180° conduction Average power = V _{F(TO)} × I _{F(AV)} + r _f × (I _{F(RMS)}) ² | | 1.29 | 1.48 | 1.28 | V | |

| BLOCKING | | | | |
|--------------------------------------|------------------|--------------------------------------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum peak reverse leakage current | I _{RRM} | T _J = 150 °C | 50 | mA |
| RMS insulation voltage | V _{INS} | 50 Hz, circuit to base, all terminals shorted, t = 1 s | 3000 | V |



| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | |
|-----------------------------------------------------------|-----------------|------------------------------------------------------------------------------------------------------------------------------------------------|-------------|---------|---------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | | | UNITS |
| | | | VSK.250 | VSK.270 | VSK.320 | |
| Maximum junction operating and storage temperature range | T_J, T_{Stg} | | - 40 to 150 | | | °C |
| Maximum thermal resistance, junction to case per junction | R_{thJC} | DC operation | 0.16 | 0.125 | | K/W |
| Maximum resistance, case to heatsink per module | R_{thCS} | Mounting surface flat, smooth and greased | 0.035 | | | |
| Mounting torque ± 10 % | MAP to heatsink | A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound. | 4 to 6 | | | Nm |
| | busbar to MAP | | 8 to 10 | | | |
| Approximate weight | | | 800 | | | g |
| | | | 30 | | | oz. |
| Case style | | | MAGN-A-PAK | | | |

| ΔR CONDUCTION PER JUNCTION | | | | | | | | | | | |
|----------------------------|----------------------------------------|-------|-------|-------|-------|-----------------------------------------|-------|-------|-------|-------|-------|
| DEVICE | SINUSOIDAL CONDUCTION AT T_J MAXIMUM | | | | | RECTANGULAR CONDUCTION AT T_J MAXIMUM | | | | | UNITS |
| | 180° | 120° | 90° | 60° | 30° | 180° | 120° | 90° | 60° | 30° | |
| VSK.250 | 0.009 | 0.010 | 0.014 | 0.020 | 0.032 | 0.007 | 0.011 | 0.015 | 0.021 | 0.033 | K/W |
| VSK.270 | 0.008 | 0.012 | 0.014 | 0.020 | 0.032 | 0.007 | 0.011 | 0.015 | 0.020 | 0.033 | |
| VSK.320 | 0.008 | 0.010 | 0.013 | 0.020 | 0.032 | 0.007 | 0.011 | 0.015 | 0.020 | 0.033 | |

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



VS-VSK.250PbF, VS-VSK.270PbF, VS-VSK.320PbF Series

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Fig. 1 - Current Ratings Characteristics



Fig. 3 - Forward Power Loss Characteristics



Fig. 2 - Current Ratings Characteristics



Fig. 4 - Forward Power Loss Characteristics



Fig. 5 - Forward Power Loss Characteristics



Fig. 6 - Forward Power Loss Characteristics



Fig. 7 - Forward Power Loss Characteristics



Fig. 8 - Maximum Non-Repetitive Surge Current



Fig. 9 - Maximum Non-Repetitive Surge Current

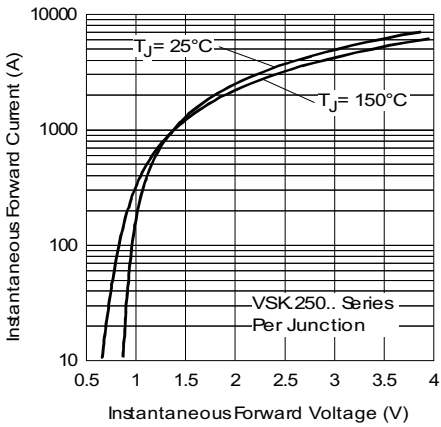


Fig. 10 - Forward Voltage Drop Characteristics

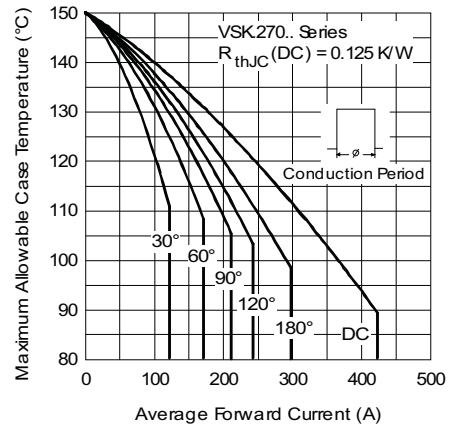


Fig. 13 - Current Ratings Characteristics

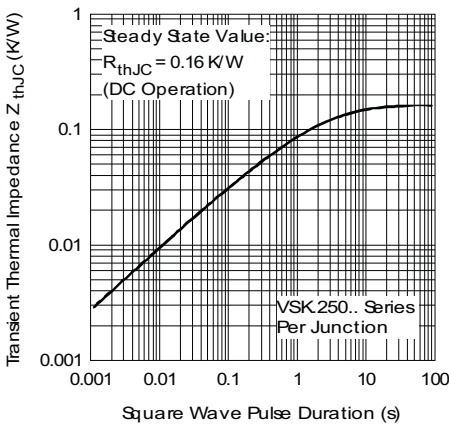


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

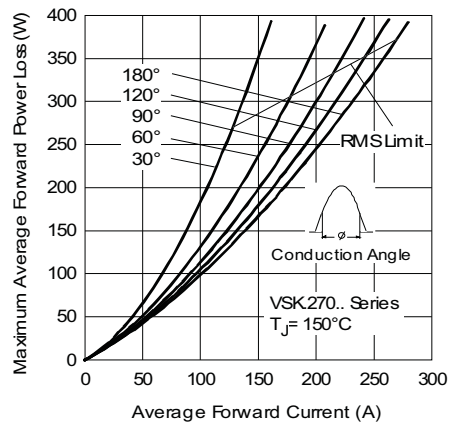


Fig. 14 - Forward Power Loss Characteristics

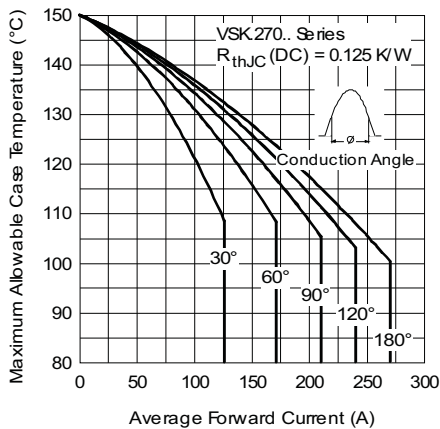


Fig. 12 - Current Ratings Characteristics

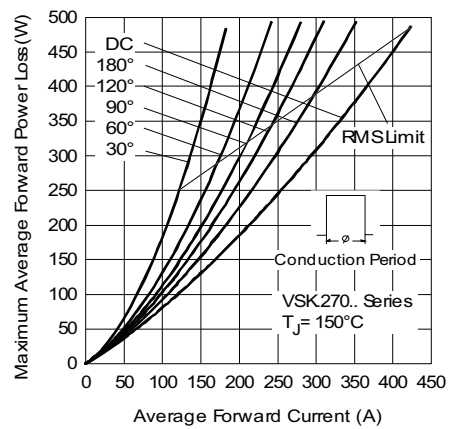


Fig. 15 - Forward Power Loss Characteristics

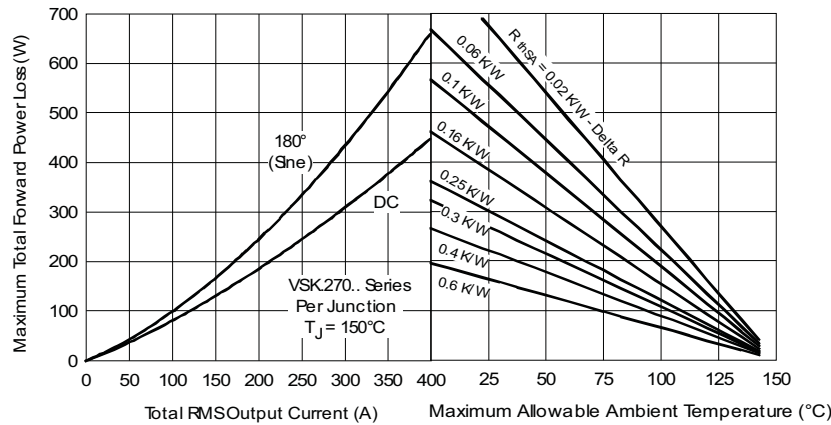


Fig. 16 - Forward Power Loss Characteristics

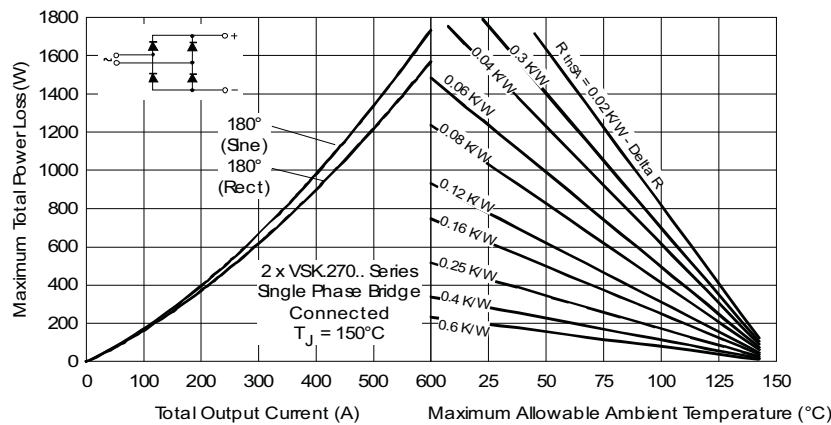


Fig. 17 - Forward Power Loss Characteristics

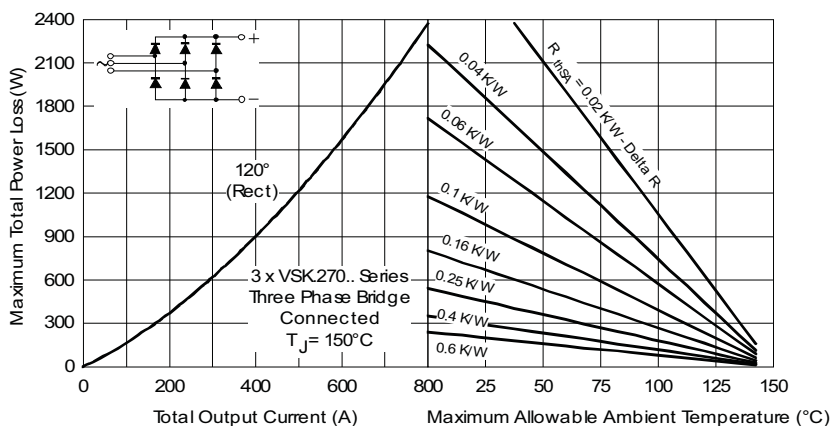


Fig. 18 - Forward Power Loss Characteristics

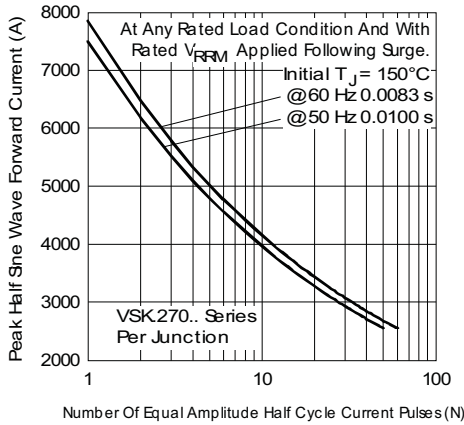


Fig. 19 - Maximum Non-Repetitive Surge Current

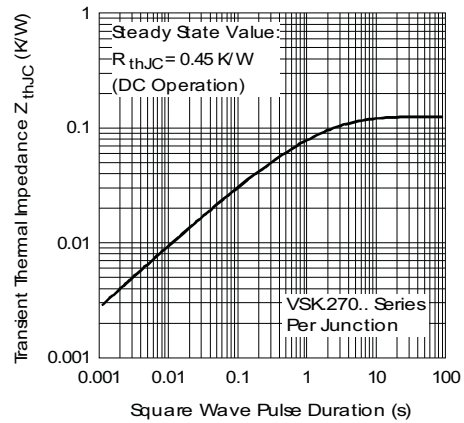


Fig. 22 - Thermal Impedance Z_{thJC} Characteristics



Fig. 20 - Maximum Non-Repetitive Surge Current

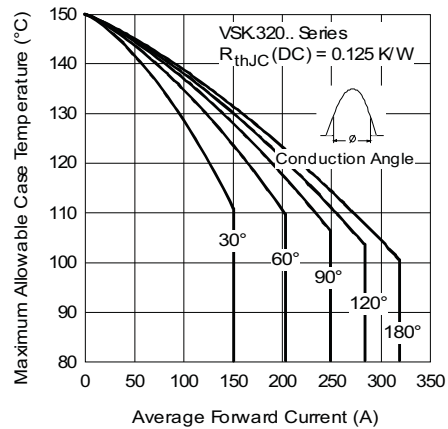


Fig. 23 - Current Ratings Characteristics



Fig. 21 - Forward Voltage Drop Characteristics



Fig. 24 - Current Ratings Characteristics



VS-VSK.250PbF, VS-VSK.270PbF, VS-VSK.320PbF Series

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Fig. 25 - Forward Power Loss Characteristics



Fig. 26 - Forward Power Loss Characteristics



Fig. 27 - Forward Power Loss Characteristics



Fig. 28 - Forward Power Loss Characteristics



Fig. 29 - Forward Power Loss Characteristics

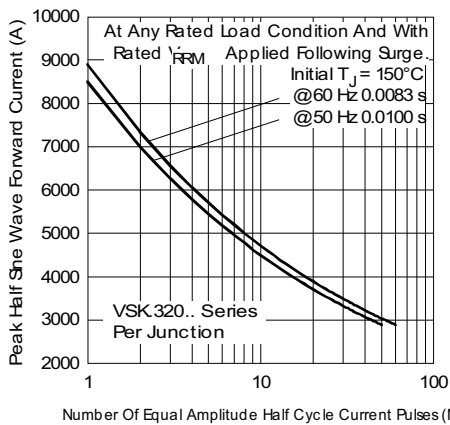


Fig. 30 - Maximum Non-Repetitive Surge Current

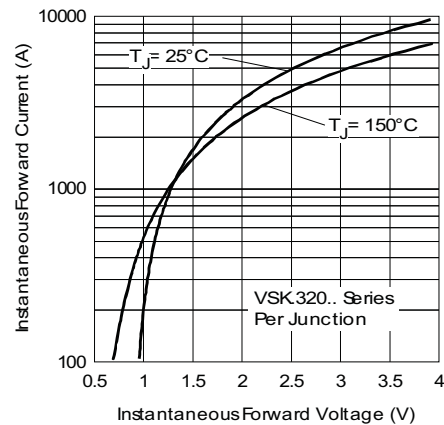


Fig. 32 - Forward Voltage Drop Characteristics

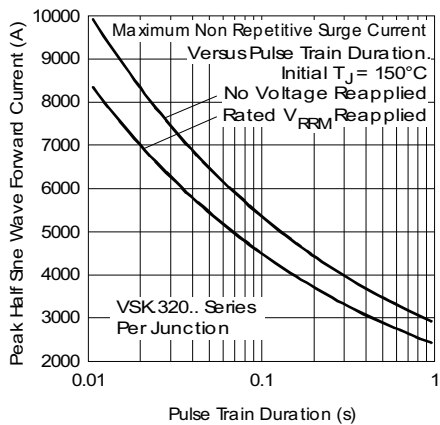


Fig. 31 - Maximum Non-Repetitive Surge Current



Fig. 33 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

| | | | | | | | |
|-------------|------------|------------|----------|------------|----------|-----------|------------|
| Device code | VS- | VSK | D | 320 | - | 24 | PbF |
|-------------|------------|------------|----------|------------|----------|-----------|------------|



- 1** - Vishay Semiconductors product
- 2** - Module type
- 3** - Circuit configuration (see Circuit Configuration table)
- 4** - Current rating: $I_{F(AV)}$ rounded
- 5** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 6** - Lead (Pb)-free

| CIRCUIT CONFIGURATION | | |
|------------------------------|-----------------------------------|------------------------|
| CIRCUIT DESCRIPTION | CIRCUIT CONFIGURATION CODE | CIRCUIT DRAWING |
| Two diodes doubler circuit | D | <p>VSKD...</p> |
| Two diodes common cathodes | C | <p>VSKC...</p> |
| Two diodes common anodes | J | <p>VSKJ...</p> |
| Single diode | E | <p>VSKE...</p> |

| LINKS TO RELATED DOCUMENTS | |
|-----------------------------------|------------------------------------------------------------------------|
| Dimensions | www.vishay.com/doc?95086 |

MAGN-A-PAK

DIMENSIONS in millimeters (inches)



Notes

- Dimensions are nominal
- Full engineering drawings are available on request
- UL identification number for gate and cathode wire: UL 1385
- UL identification number for package: UL 94 V-0



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